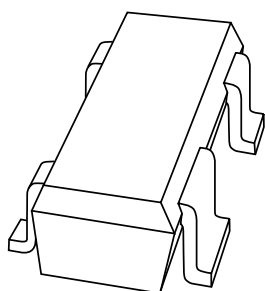


DATA SHEET



BFG25AW; BFG25AW/X NPN 5 GHz wideband transistors

Product specification
Supersedes data of August 1995

1998 Sep 23



NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X

FEATURES

- Low current consumption (100 μ A to 1 mA)
- Low noise figure
- Gold metallization ensures excellent reliability.

APPLICATIONS

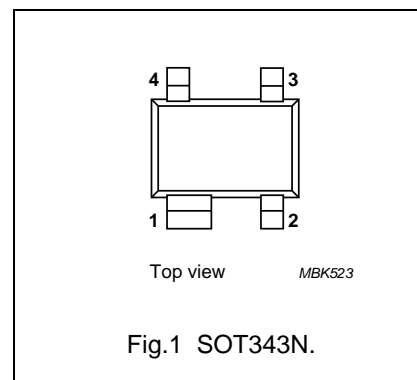
Wideband applications in UHF low power amplifiers, such as pocket telephones and paging systems.

DESCRIPTION

NPN silicon planar epitaxial transistor in a 4-pin dual-emitter SOT343N plastic package.

PINNING

PIN	DESCRIPTION
BFG25AW	
1	collector
2	base
3	emitter
4	emitter
BFG25AW/X	
1	collector
2	emitter
3	base
4	emitter



MARKING

TYPE NUMBER	CODE
BFG25AW	N6
BFG25AW/X	V1

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	–	8	V
V_{CEO}	collector-emitter voltage	open base	–	–	5	V
I_C	collector current (DC)		–	–	6.5	mA
P_{tot}	total power dissipation	$T_s \leq 85\text{ }^\circ\text{C}$	–	–	500	mW
h_{FE}	DC current gain	$I_C = 0.5\text{ mA}; V_{CE} = 1\text{ V}$	50	80	200	
C_{re}	feedback capacitance	$I_C = 0; V_{CE} = 1\text{ V}; f = 1\text{ MHz}$	–	0.2	0.3	pF
f_T	transition frequency	$I_C = 1\text{ mA}; V_{CE} = 1\text{ V}; f = 500\text{ MHz}; T_{amb} = 25\text{ }^\circ\text{C}$	3.5	5	–	GHz
G_{UM}	maximum unilateral power gain	$I_C = 0.5\text{ mA}; V_{CE} = 1\text{ V}; f = 1\text{ GHz}; T_{amb} = 25\text{ }^\circ\text{C}$	–	16	–	dB
F	noise figure	$\Gamma_s = \Gamma_{opt}; I_C = 1\text{ mA}; V_{CE} = 1\text{ V}; f = 1\text{ GHz}$	–	2	–	dB

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	8	V
V_{CEO}	collector-emitter voltage	open base	–	5	V
V_{EBO}	emitter-base voltage	open collector	–	2	V
I_C	collector current (DC)		–	6.5	mA
P_{tot}	total power dissipation	$T_s \leq 85\text{ }^\circ\text{C};$ see Fig.2; note 1	–	500	mW
T_{stg}	storage temperature		–65	+150	$^\circ\text{C}$
T_j	junction temperature		–	175	$^\circ\text{C}$

Note

1. T_s is the temperature at the soldering point of the collector pin.

NPN 5 GHz wideband transistors

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to soldering point	$T_s \leq 85\text{ °C}$; note 1	180	K/W

Note

- T_s is the temperature at the soldering point of the collector pin.

CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

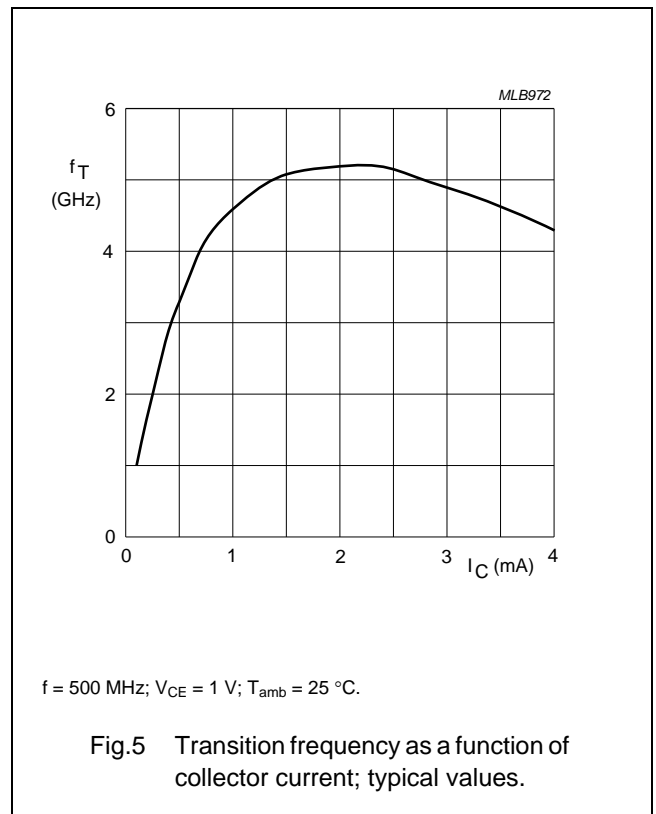
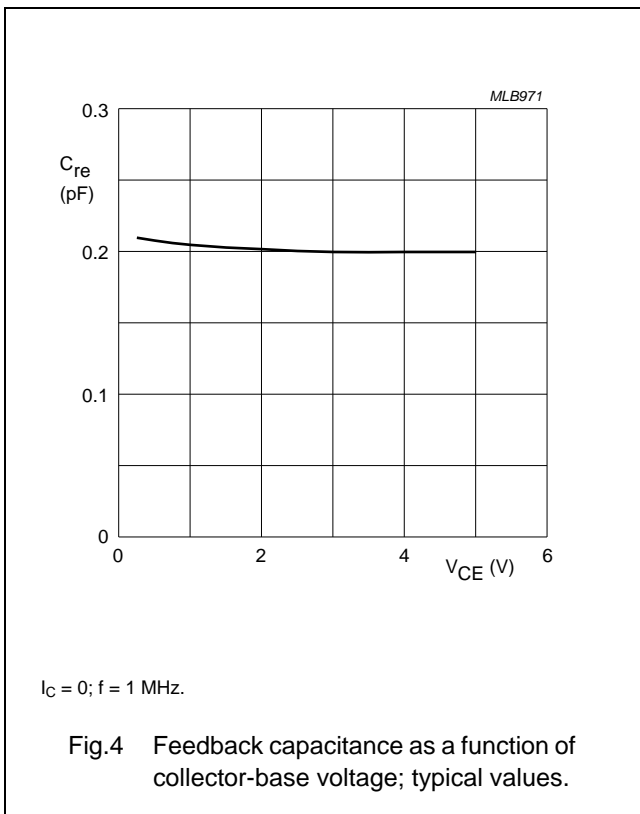
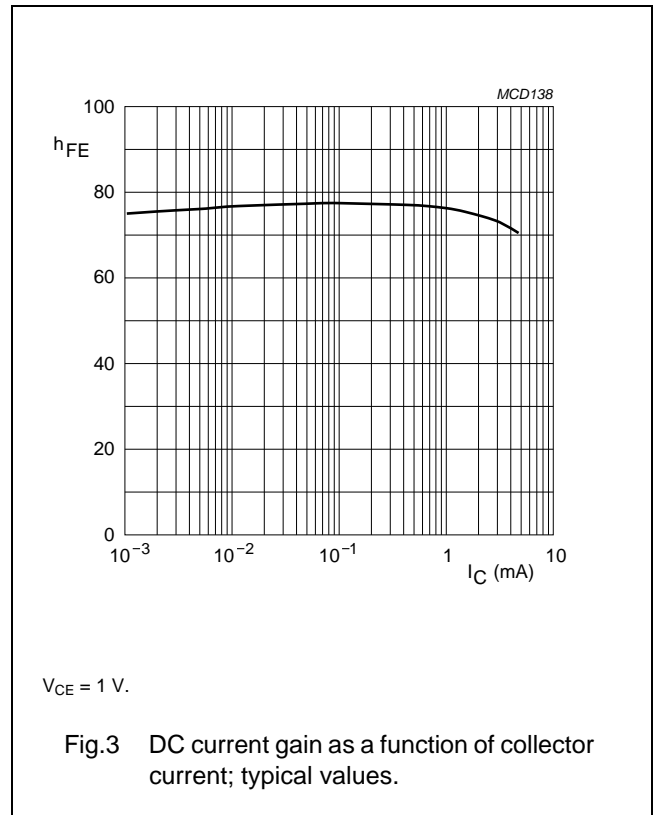
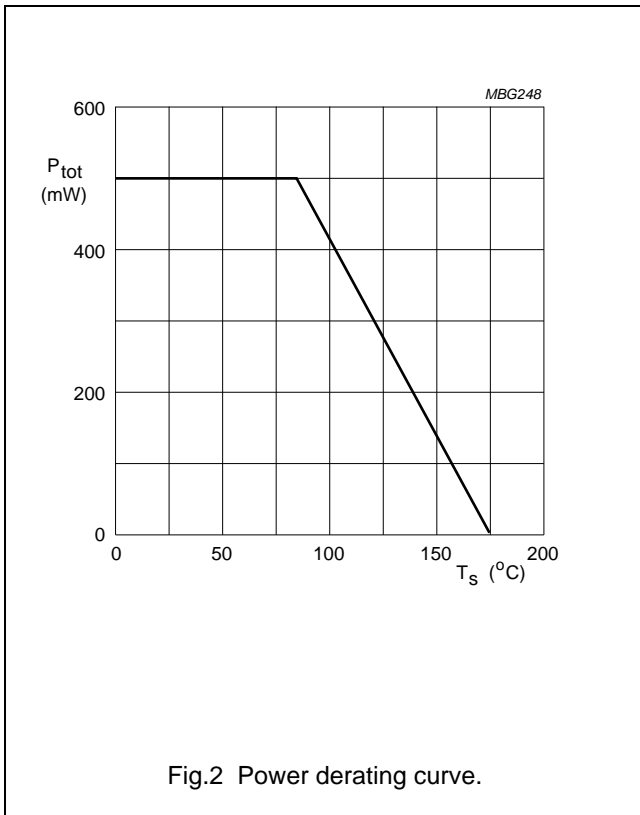
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100\ \mu\text{A}$; $I_E = 0$	–	–	8	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 1\ \text{mA}$; $I_B = 0$	–	–	5	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_E = 100\ \mu\text{A}$; $I_C = 0$	–	–	2	V
I_{CBO}	collector leakage current	open emitter; $V_{CB} = 5\ \text{V}$; $I_E = 0$	–	–	50	nA
h_{FE}	DC current gain	$I_C = 0.5\ \text{mA}$; $V_{CE} = 1\ \text{V}$	50	80	200	
C_{re}	feedback capacitance	$I_C = 0$; $V_{CE} = 1\ \text{V}$; $f = 1\ \text{MHz}$	–	0.2	0.3	pF
f_T	transition frequency	$I_C = 1\ \text{mA}$; $V_{CE} = 1\ \text{V}$; $f = 1\ \text{GHz}$; $T_{amb} = 25\text{ °C}$	3.5	5	–	GHz
G_{UM}	maximum unilateral power gain; note 1	$I_C = 0.5\ \text{mA}$; $V_{CE} = 1\ \text{V}$; $f = 1\ \text{GHz}$; $T_{amb} = 25\text{ °C}$	–	16	–	dB
		$I_C = 0.5\ \text{mA}$; $V_{CE} = 1\ \text{V}$; $f = 2\ \text{GHz}$; $T_{amb} = 25\text{ °C}$	–	8	–	dB
F	noise figure	$\Gamma_s = \Gamma_{opt}$; $I_C = 0.5\ \text{mA}$; $V_{CE} = 1\ \text{V}$; $f = 1\ \text{GHz}$	–	1.9	–	dB
		$\Gamma_s = \Gamma_{opt}$; $I_C = 1\ \text{mA}$; $V_{CE} = 1\ \text{V}$; $f = 1\ \text{GHz}$	–	2	–	dB

Note

- G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero. $G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)}$ dB.

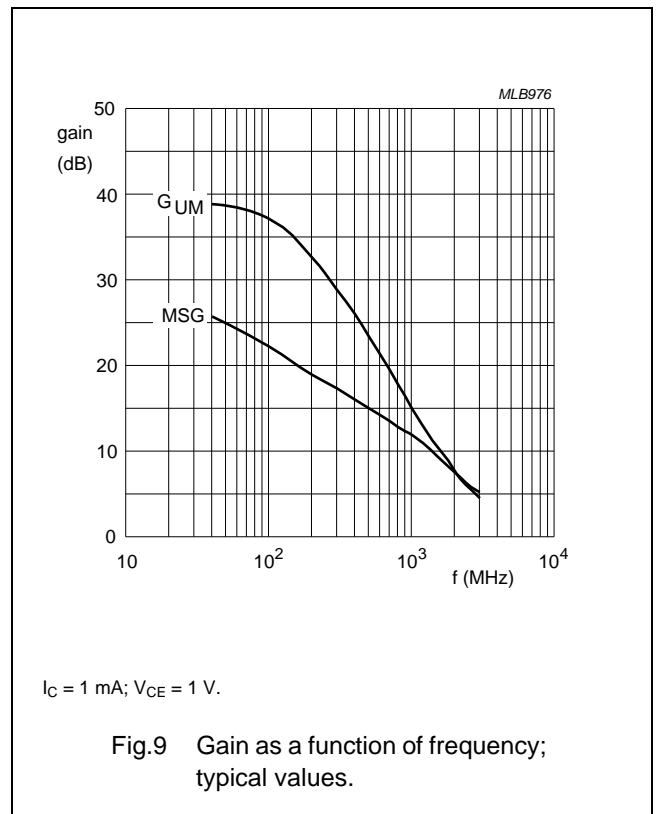
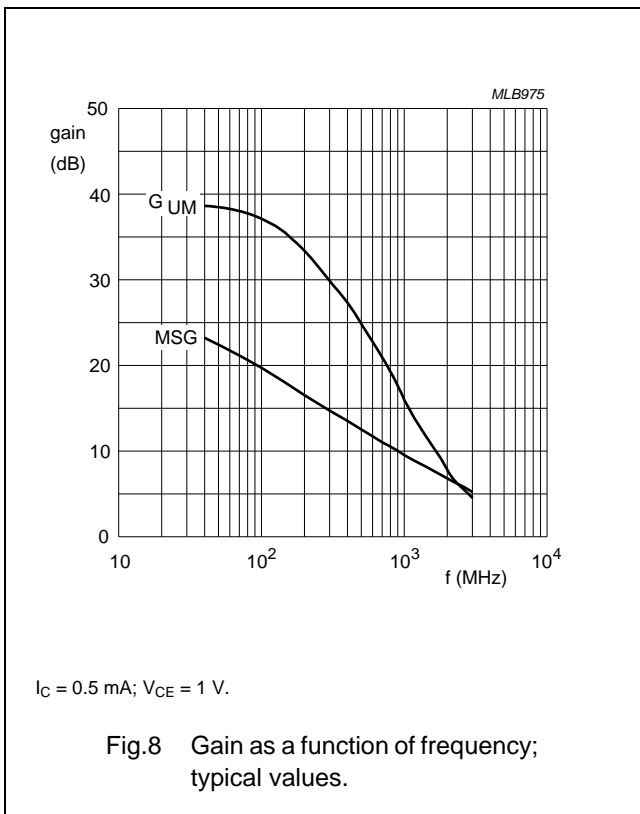
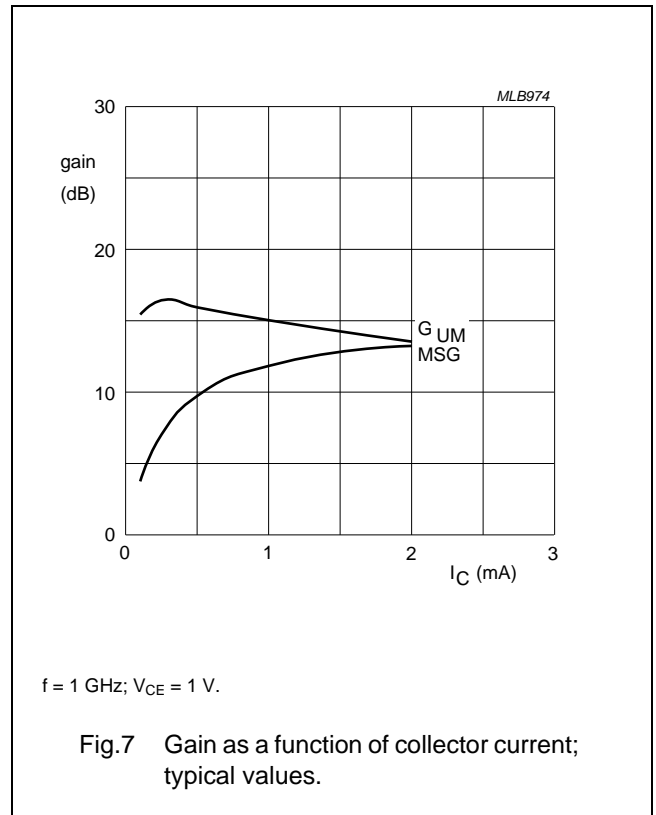
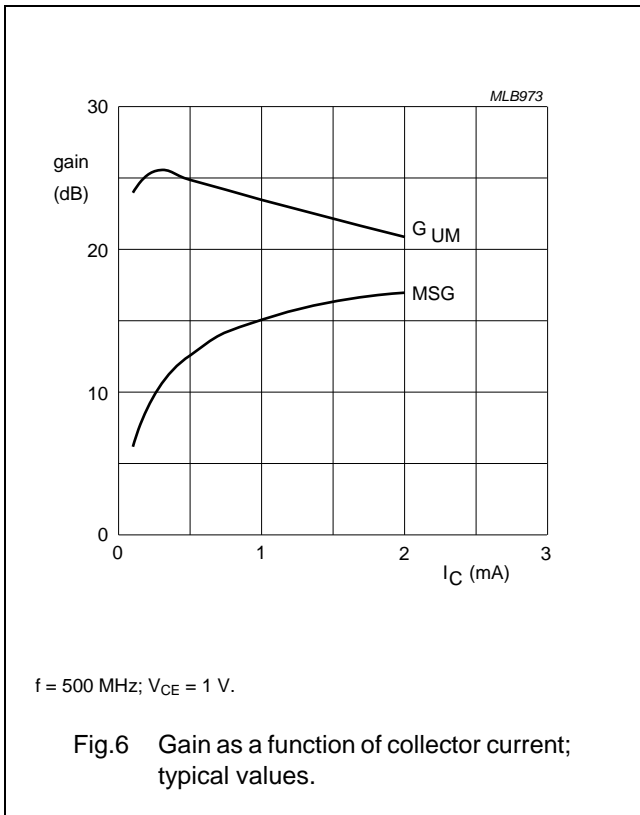
NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X



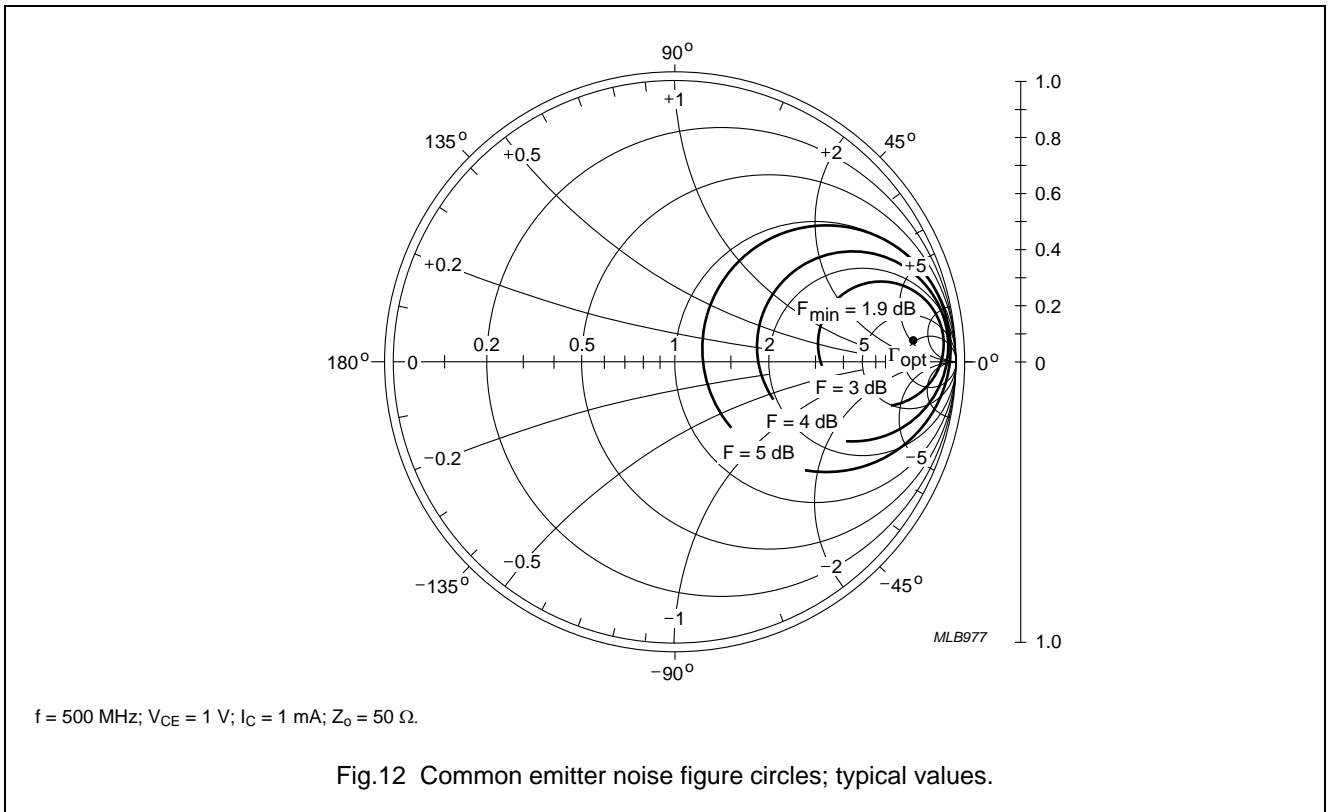
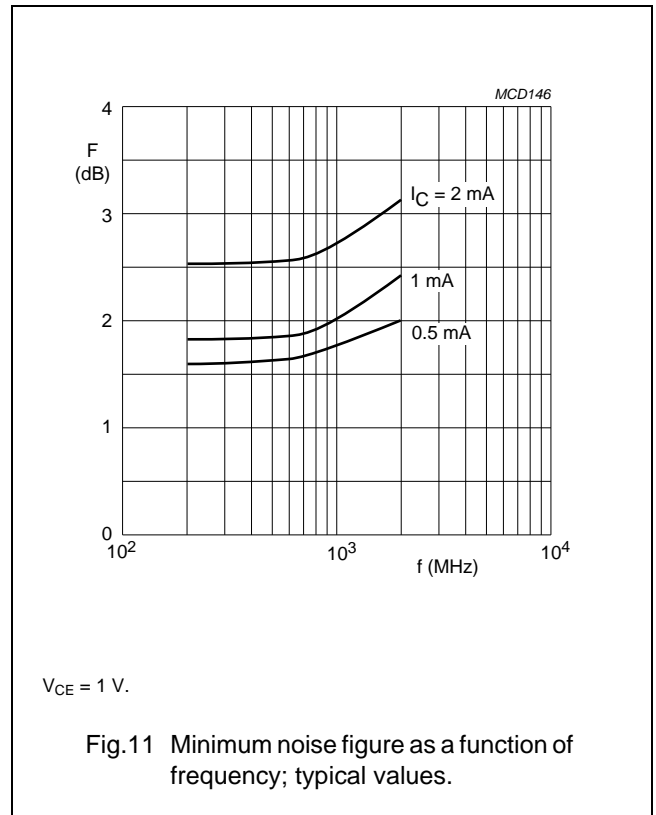
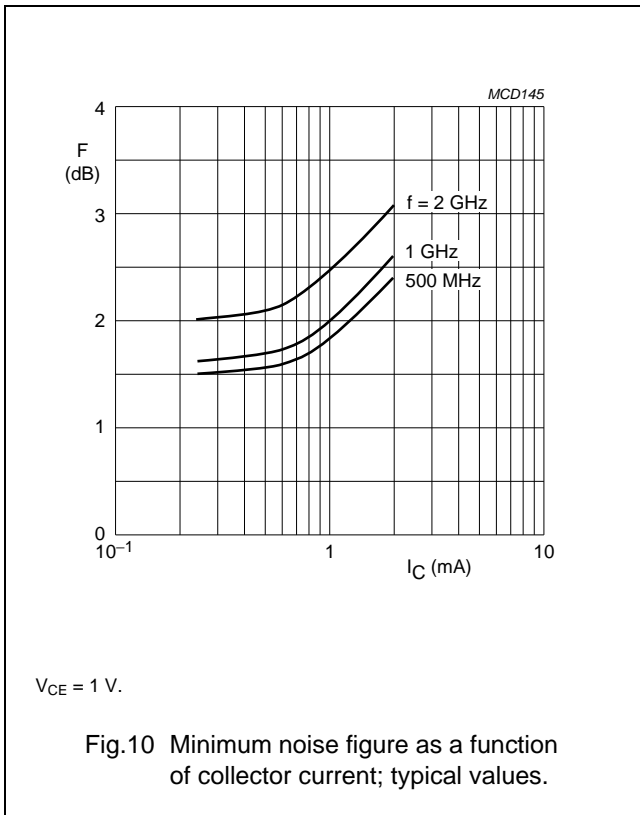
NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X



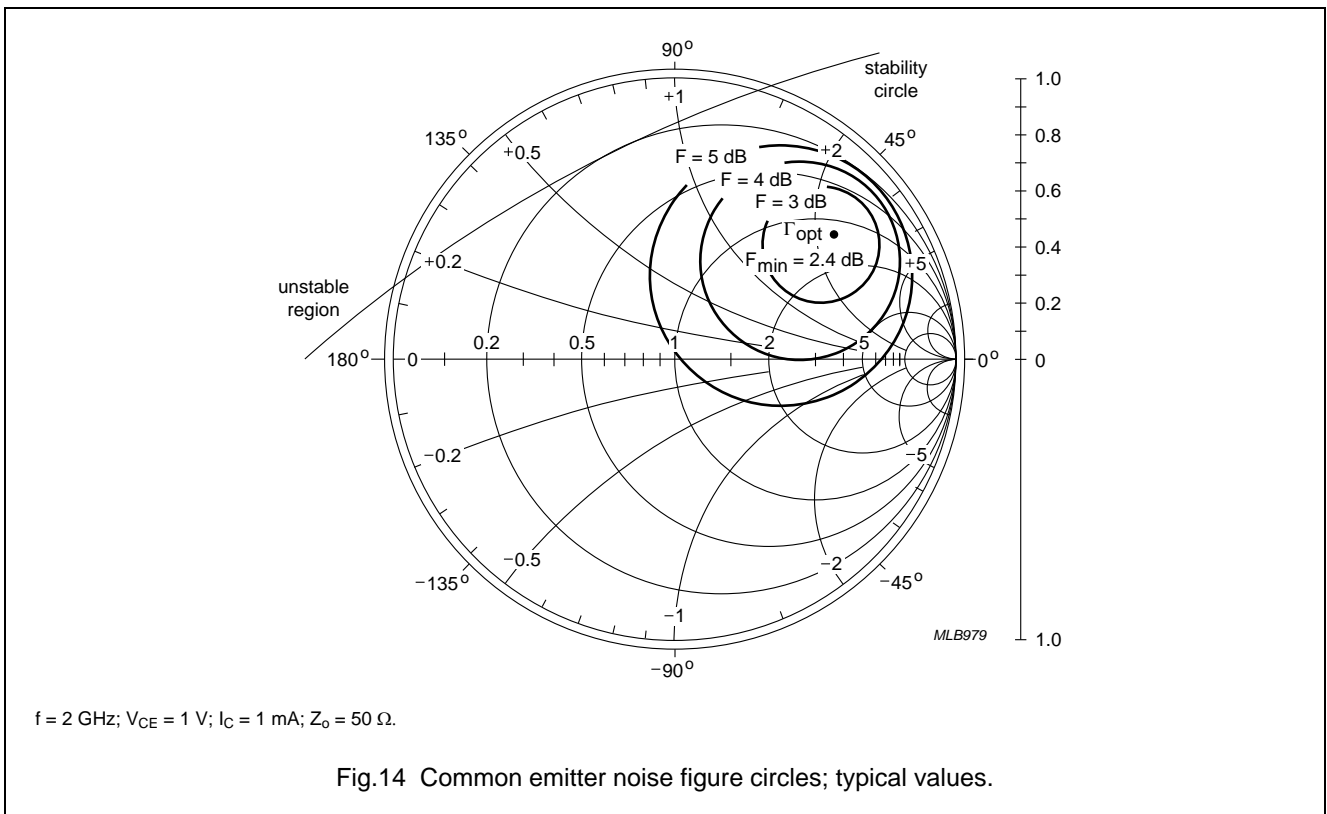
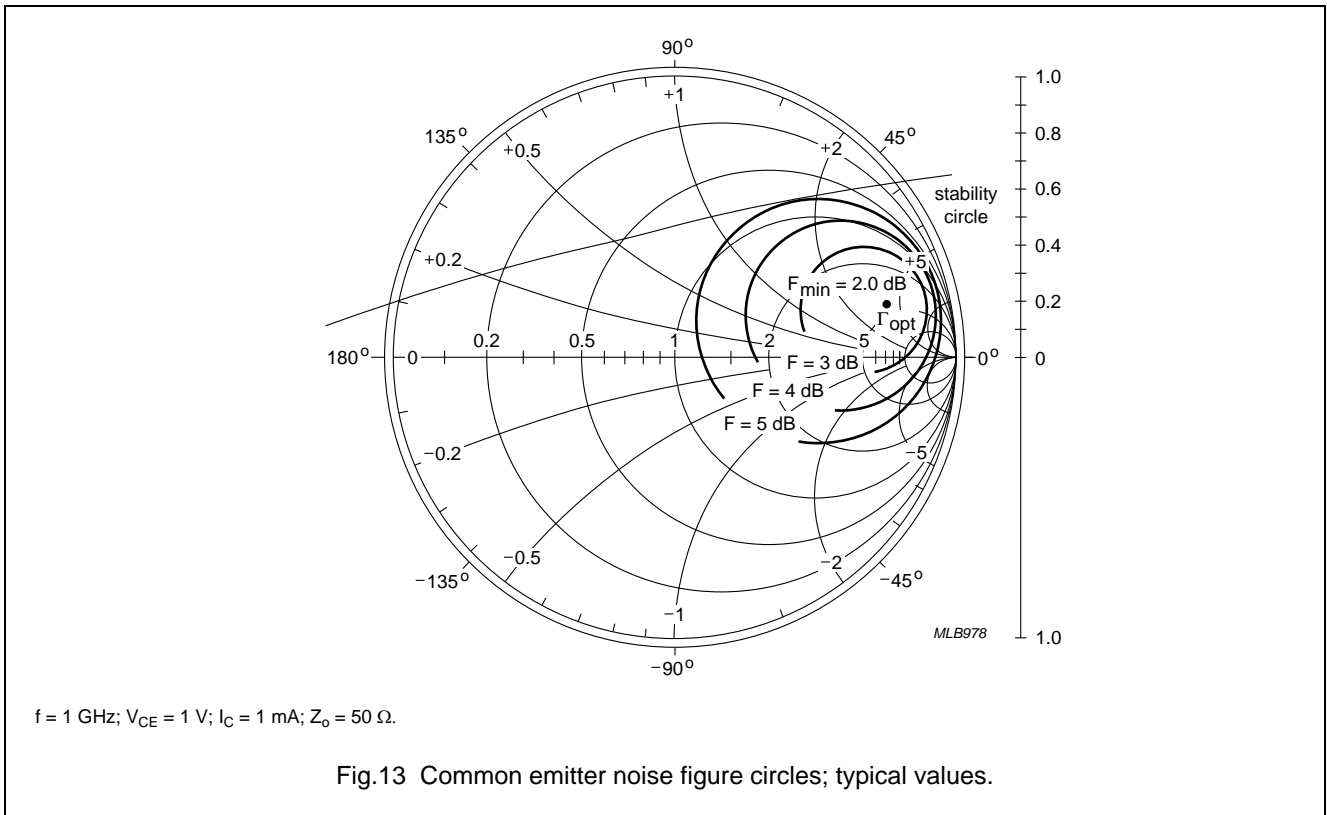
NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X



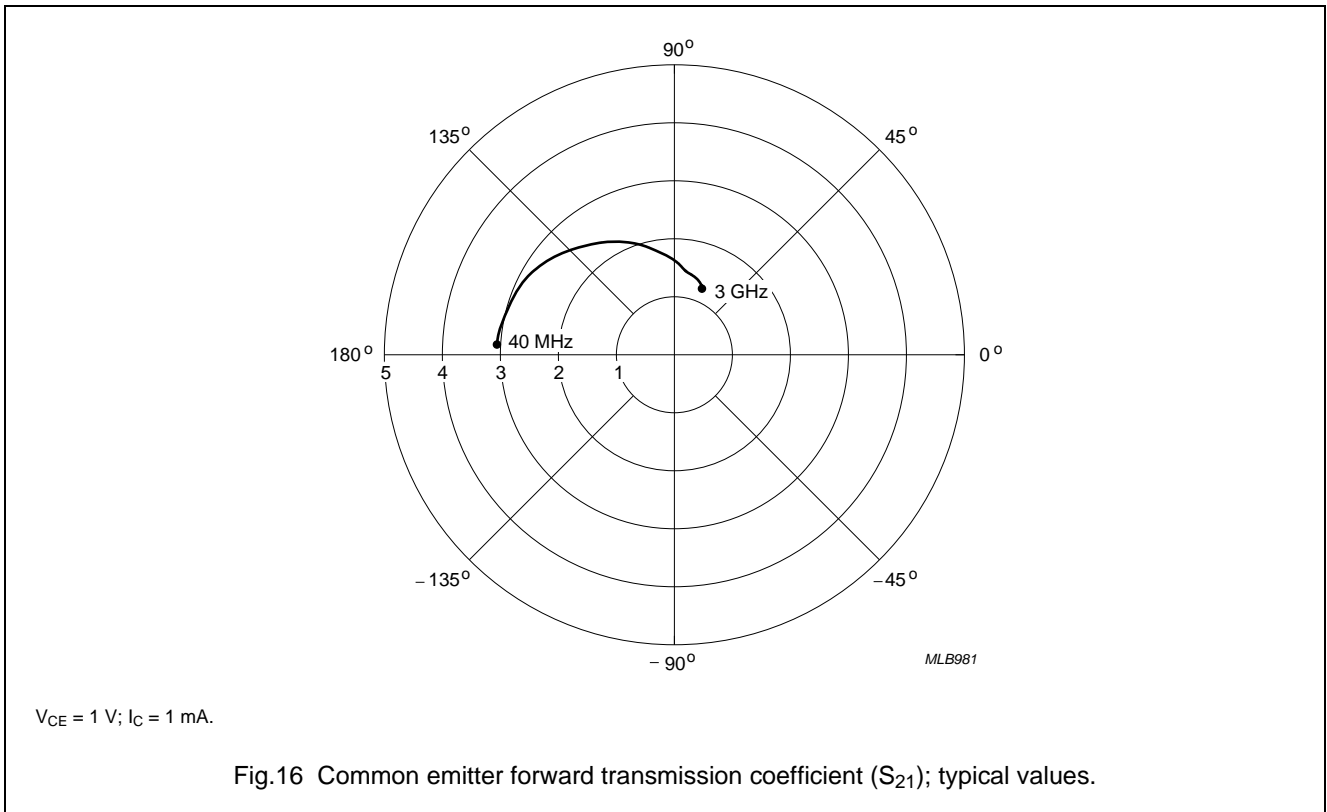
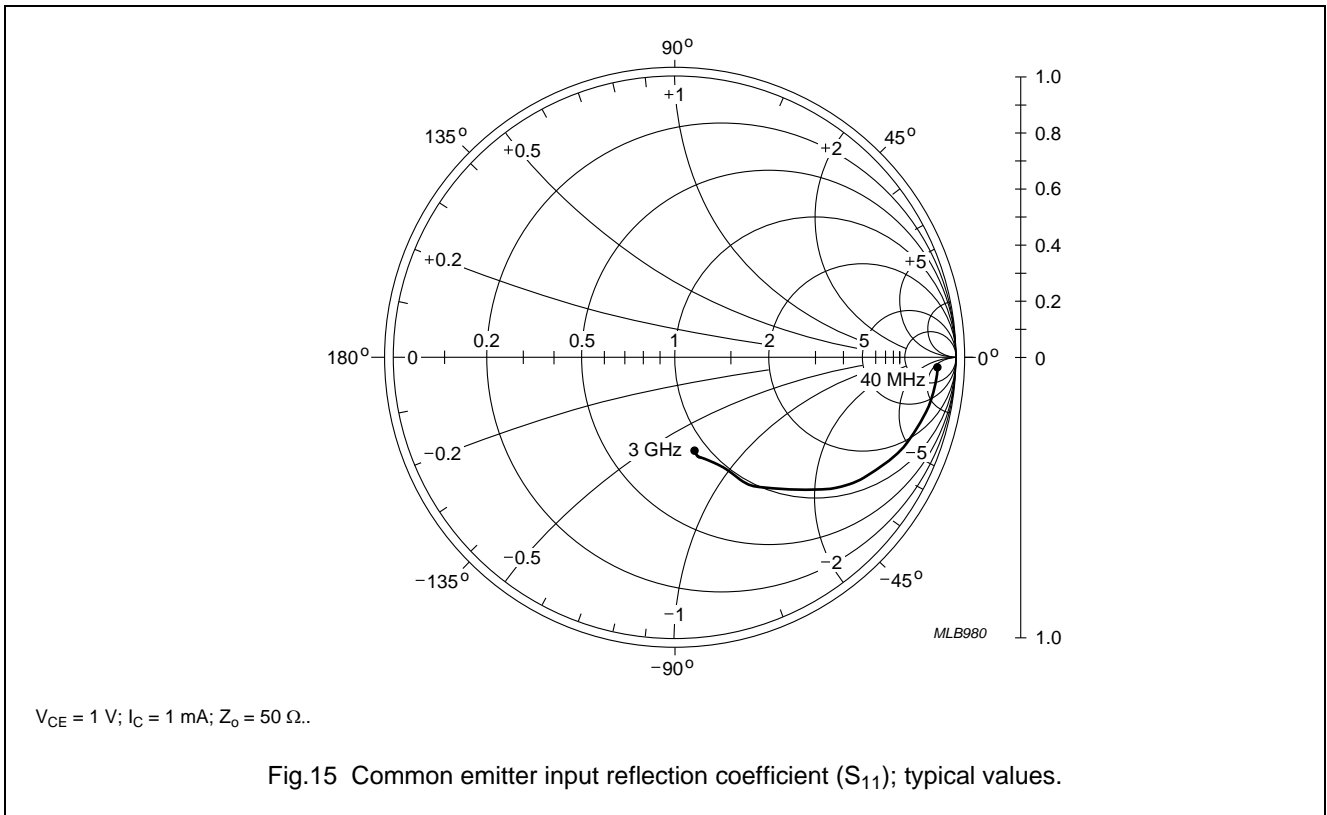
NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X



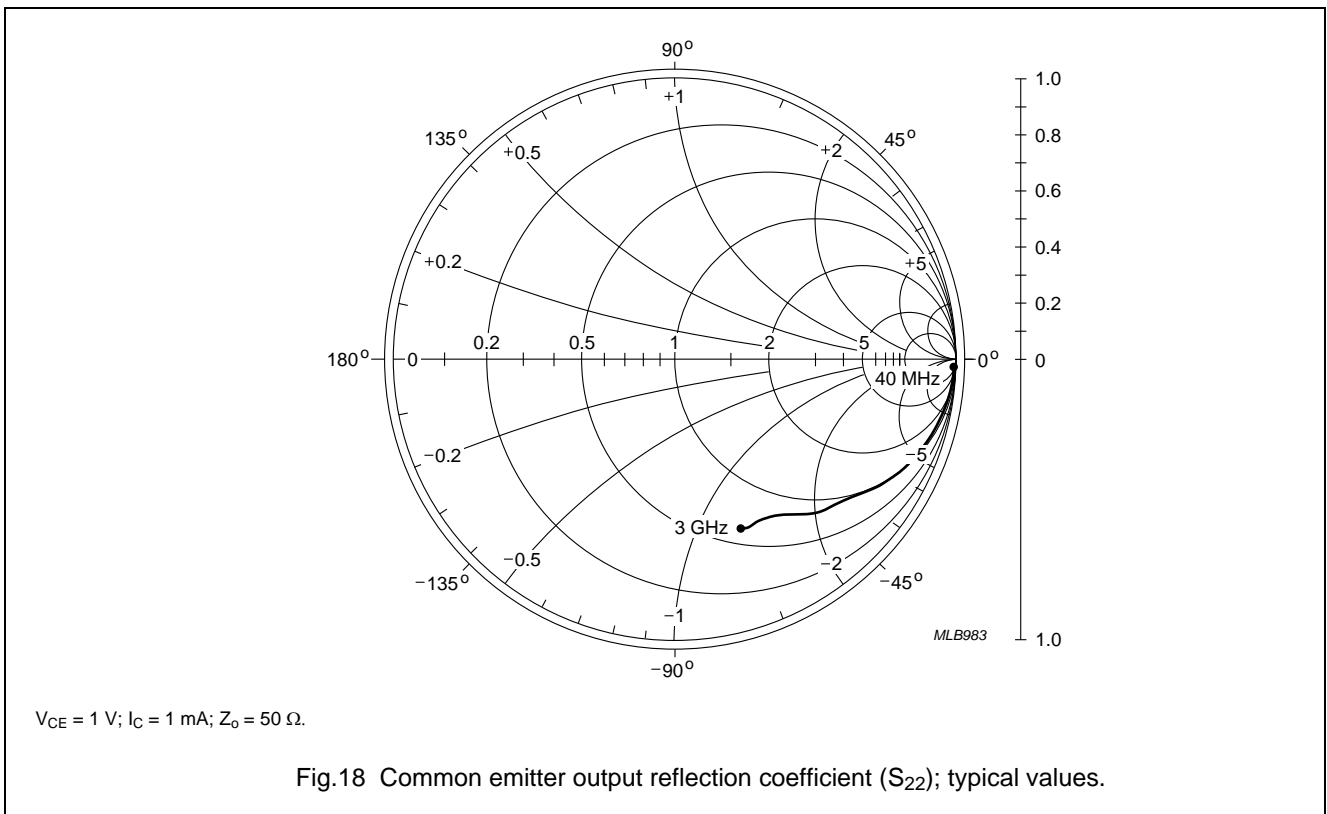
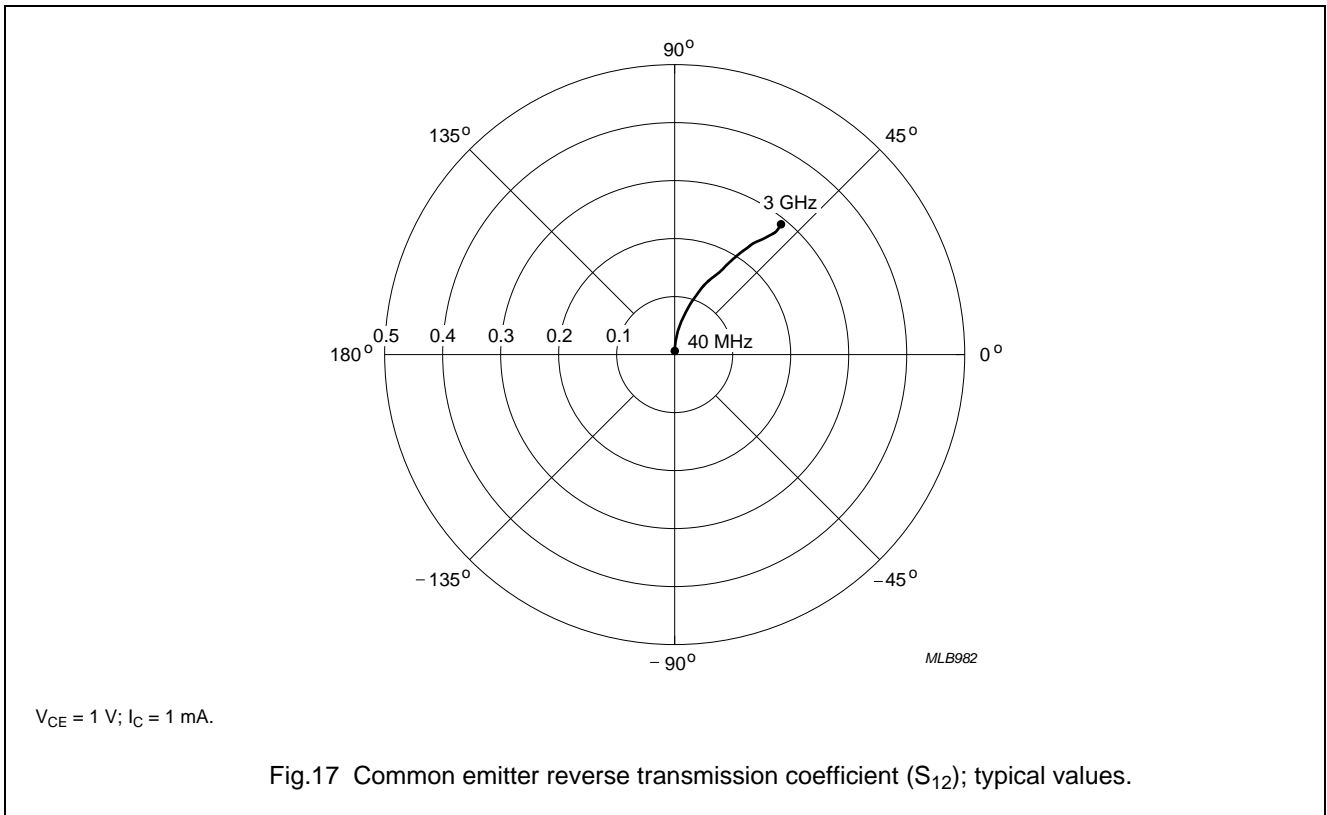
NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X



NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X



NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X

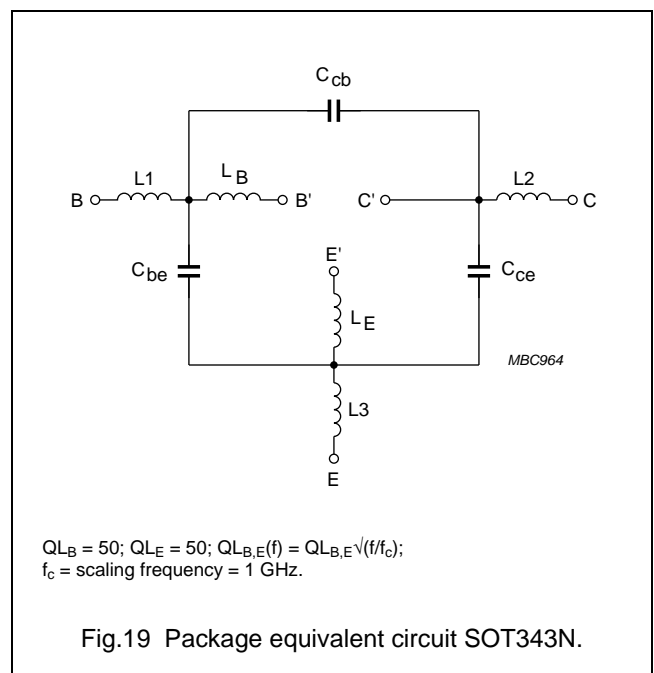
SPICE parameters for the BFG25W crystal

SEQUENCE No.	PARAMETER	VALUE	UNIT
1	IS	13.77	aA
2	BF	85.65	–
3	NF	0.980	–
4	VAF	50.80	V
5	IKF	10.00	A
6	ISE	2.199	fA
7	NE	1.857	–
8	BR	16.97	–
9	NR	0.986	–
10	VAR	2.491	V
11	IKR	188.0	mA
12	ISC	205.1	aA
13	NC	1.107	–
14	RB	80.00	Ω
15	IRB	1.000	μA
16	RBM	80.00	Ω
17	RE	7.911	Ω
18	RC	5.300	Ω
19 ⁽¹⁾	XTB	0.000	–
20 ⁽¹⁾	EG	1.110	eV
21 ⁽¹⁾	XTI	3.000	–
22	CJE	223.0	fF
23	VJE	669.7	mV
24	MJE	0.060	–
25	TF	5.112	ps
26	XTF	7.909	–
27	VTF	1.338	V
28	ITF	5.662	mA
29	PTF	15.37	deg
30	CJC	229.0	fF
31	VJC	394.7	mV
32	MJC	0.043	–
33	XCJC	0.050	–
34	TR	13.26	ns
35 ⁽¹⁾	CJS	0.000	F

SEQUENCE No.	PARAMETER	VALUE	UNIT
36 ⁽¹⁾	VJS	750.0	mV
37 ⁽¹⁾	MJS	0.000	–
38	FC	0.988	–

Note

1. These parameters have not been extracted, the default values are shown.



List of components (see Fig.19)

DESIGNATION	VALUE	UNIT
C_{be}	70	fF
C_{cb}	50	fF
C_{ce}	115	fF
L1	0.34	nH
L2	0.10	nH
L3	0.25	nH
L_B	0.40	nH
L_E	0.40	nH

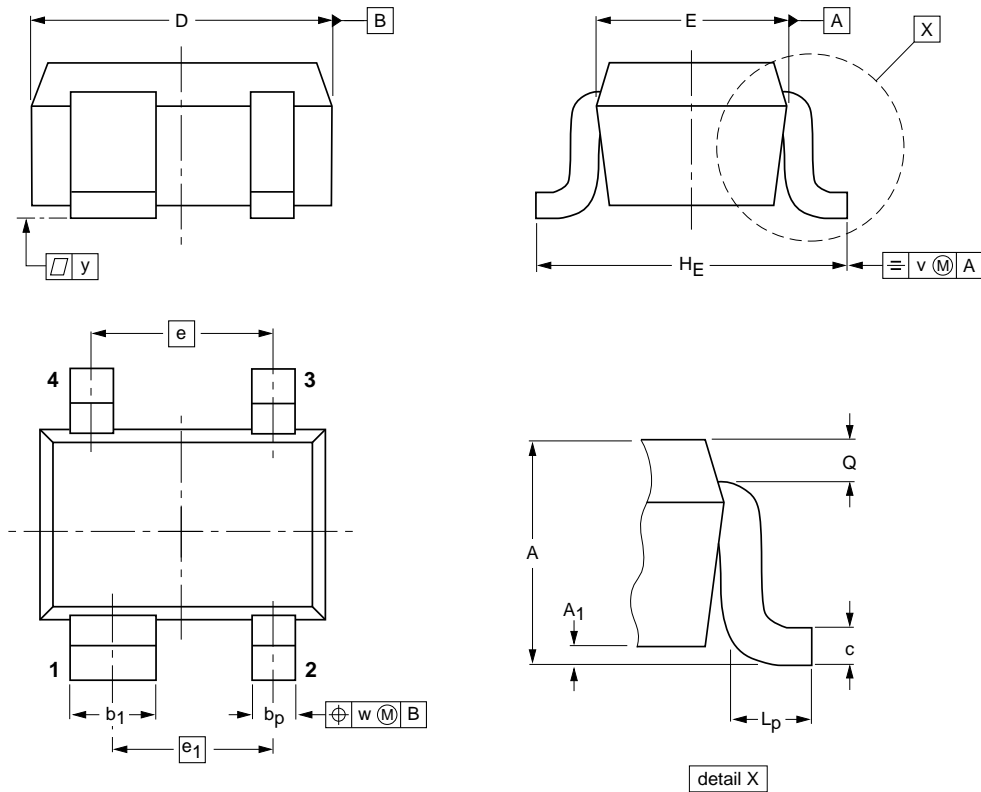
NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X

PACKAGE OUTLINES

Plastic surface-mounted package; 4 leads

SOT343N



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	b ₁	c	D	E	e	e ₁	H _E	L _p	Q	v	w	y
mm	1.1 0.8	0.1	0.4 0.3	0.7 0.5	0.25 0.10	2.2 1.8	1.35 1.15	1.3	1.15	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT343N						97-05-21- 06-03-16

NPN 5 GHz wideband transistors

BFG25AW; BFG25AW/X

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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BFG25AW; BFG25AW/X

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: <http://www.nxp.com>

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